
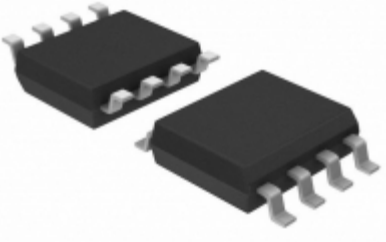
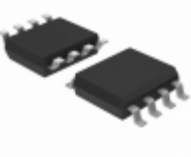

	<h2>SI4322DY-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI4322DY-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 18A 8-SOIC</p> <p>Datenblätter:  SI4322DY-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 34580 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4322DY-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 18A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	34580 pcs Stock
detaillierte Beschreibung	N-Channel 30V 18A (Tc) 3.1W (Ta), 5.4W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	3.1W (Ta), 5.4W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	18A (Tc)
Rds On (Max) @ Id, Vgs	8.5 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1640pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI4322DY-T1-E3DKR

SI4322DY-T1-E3 ist neu im Original, Suche SI4322DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4322DY-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI4322DY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4322DY-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 18A 8-SOIC</p>	 <p>SI4324DY VIS SI4324DY VIS</p>	 <p>SI4324DY-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 36A 8-SOIC</p>	 <p>SI4322DY-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 18A 8-SOIC</p>
 <p>SI4324DY-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 36A 8-SOIC</p>	 <p>SI4322-A0-FTR Energy Micro (Silicon Labs) IC RX FSK UNI 868/915MHZ 16TSSOP</p>	 <p>SI4322DY-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 18A 8-SOIC</p>	 <p>SI4322-A1-FT Energy Micro (Silicon Labs) IC RCVR FSK 915MHZ 3.8V 16-TSSOP</p>

heiße Teile

Mehr

SI4228DY-T1-E3	SI4228DY-T1-GE3	SI4228DY-T1-GE3	SI4232DY.	SI4276DY-T1-E3
SI4276DY-T1-E3	SI4282DVP	SI4286DY	SI4286DY-T1-GE3	SI4286DY-T1-GE3
SI4288DY	SI4288DY-T1-GE3	SI4288DY-T1-GE3	SI4300-BM	SI4300-E-BM
SI4300DY-T1-E3	SI4308DY-T1	SI4308DY-T1-E3	SI4311-B21-GMR	SI4320-J1-FTR
SI4320DY	SI4320DY-T1-E3	SI4320DY-T1-E3	SI4322-A0-FT	SI4322-A0-FTR
SI4322DY-T1-E3	SI4324DY	SI4324DY-T1-E3	SI4324DY-T1-E3	SI4326DY-T1-E3
SI4330BDY-T1-GE3	SI4330DY-T1	SI4330DY-T1-E3	SI4330DY-T1-E3	SI4330DY-T1-E3.
SI4334DY-T1-E3	SI4336DY	SI4336DY-E3	SI4336DY-T1-E3	SI4336DY-T1-E3
SI4340CDY-T1-E3	SI4340CDY-T1-E3	SI4340CDY-T1-E3-S	SI4340DY	SI4340DY-T1
SI4340DY-T1-E3	SI4340DY-T1-E3	SI4346DY	SI4346DY-T1-E3	SI4346DY-T1-E3

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